74AHC2G241-Q100; 74AHCT2G241-Q100

Dual buffer/line driver; 3-state Rev. 2 — 16 January 2019

Product data sheet

1. General description

The 74AHC2G241-Q100; 74AHCT2G241-Q100 is a high-speed Si-gate CMOS device.

The 74AHC2G241-Q100; 74AHCT2G241-Q100 is a dual non-inverting buffer/line driver with 3state outputs. The 3-state outputs are controlled by the output enable inputs $1\overline{OE}$ and 2OE. A HIGH level at pin $1\overline{OE}$ causes output 1Y to assume a high-impedance OFF-state. A LOW level at pin 2OE causes output 2Y to assume a high-impedance OFF-state. Schmitt-trigger action at all inputs makes the circuit highly tolerant for slower input rise and fall times.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Symmetrical output impedance
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Low power dissipation
- Balanced propagation delays

3. Ordering information

Table 1. Ordering information										
Type number	Package									
	Temperature range	Name	Description	Version						
74AHC2G241DP-Q100	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2						
74AHC2G241DC-Q100	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads;	SOT765-1						
74AHCT2G241DC-Q100			body width 2.3 mm							

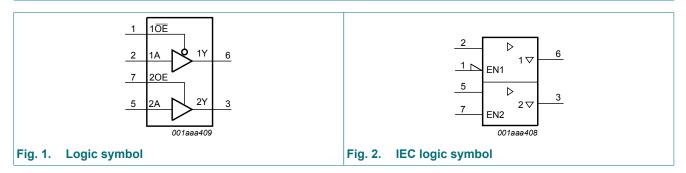
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4. Marking

Table 2. Marking							
Type number	Marking code[1]						
74AHC2G241DP-Q100	A241						
74AHC2G241DC-Q100	A41						
74AHCT2G241DC-Q100	C41						

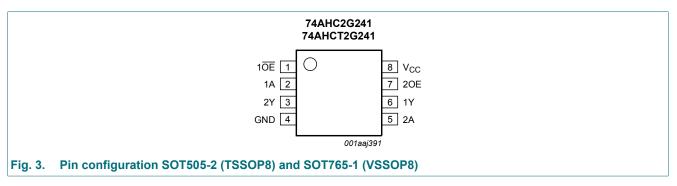
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description		
Symbol	Pin	Description
1 0E	1	output enable input (active LOW)
1A	2	data input
2Y	3	data output
GND	4	ground (0 V)
2A	5	data input
1Y	6	data output
20E	7	output enable input (active HIGH)
V _{CC}	8	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

-		Output	Input	Output	
1 0E	1A	1Y	20E	2A	2Y
L	L	L	Н	L	L
L	Н	Н	Н	Н	Н
Н	Х	Z	L	Х	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
VI	input voltage			-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	[1]	-20	-	mA
I _{ОК}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	$-0.5 V < V_O < V_{CC} + 0.5 V$		-	±25	mA
I _{CC}	supply current			-	75	mA
I _{GND}	ground current			-75	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T_{amb} = -40 °C to +125 °C	[2]	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K. For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly with 8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AH	C2G241	-Q100	74AH	Unit		
			Min	Тур	Мах	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	V_{CC} = 3.3 V ± 0.3 V	-	-	100	-	-	-	ns/V
	and fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC2	G241-Q100	1								-1
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -50 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -50 μA; V _{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I _O = -50 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		I_{O} = -8.0 mA; V_{CC} = 4.5 V	3.94	-	-	3.8	-	3.70	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}								
		I _O = 50 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I _{OZ}	OFF-state output current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	0.25	-	2.5	-	10	μA
I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	1.0	-	10	-	40	μA
CI	input capacitance		-	1.5	10	-	10	-	10	pF

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHCT	2G241-Q100	·						1		
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
output voltage	Ι _Ο = -50 μΑ	4.4	4.5	-	4.4	-	4.4	-	V	
		I _O = -8.0 mA	3.94	-	-	3.8	-	3.70	-	V
- OL -	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		l _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
I _{OZ}	OFF-state output current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	0.25	-	2.5	-	10	μA
l _l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	1.0	-	10	-	40	μA
ΔI _{CC}	additional supply current	per input pin; V _I = 3.4 V; other inputs at V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
Cı	input capacitance		-	1.5	10	-	10	-	10	pF

74AHC_AHCT2G241_Q100

11. Dynamic characteristics

Table 8. Dynamic characteristics

GND = 0 V; for test circuit see Fig. 7.

Symbol	Parameter	Conditions			25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
				Min	Тур	Max	Min	Мах	Min	Мах	-
74AHC2	G241-Q100						1				1
t _{pd}	propagation	nA to nY; see Fig. 4	[1]								
	delay	V _{CC} = 3.0 V to 3.6 V	[2]								
		C _L = 15 pF		-	4.7	8.0	1.0	9.5	1.0	11.5	ns
		C _L = 50 pF		-	6.6	11.5	1.0	13.0	1.0	14.5	ns
		V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	3.4	5.5	1.0	6.5	1.0	7.0	ns
		C _L = 50 pF		-	4.7	7.5	1.0	8.5	1.0	9.5	ns
t _{en}	enable time	1OE to 1Y; see Fig. 5	[1]								
		V _{CC} = 3.0 V to 3.6 V	[2]								
		C _L = 15 pF		-	5.0	8.0	1.0	9.5	1.0	11.5	ns
		C _L = 50 pF		-	6.9	11.5	1.0	13.0	1.0	14.5	ns
		V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	3.6	5.1	1.0	6.0	1.0	6.5	ns
		C _L = 50 pF		-	4.9	7.5	1.0	8.5	1.0	9.5	ns
		2OE to 2Y; see Fig. 6	[1]								
		V _{CC} = 3.0 V to 3.6 V	[2]								
		C _L = 15 pF		-	4.9	8.0	1.0	9.5	1.0	10.0	ns
		C _L = 50 pF		-	7.0	11.5	1.0	13.0	1.0	14.5	ns
		V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	3.6	5.6	1.0	6.3	1.0	7.0	ns
		C _L = 50 pF		-	5.4	8.0	1.0	9.0	1.0	9.5	ns
t _{dis}	disable time	10E to 1Y; see Fig. 5	[1]								
		V _{CC} = 3.0 V to 3.6 V	[2]								
		C _L = 15 pF		-	6.0	9.7	1.0	11.5	1.0	12.5	ns
		C _L = 50 pF		-	8.3	13.2	1.0	15.0	1.0	16.5	ns
		V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	4.1	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF		-	5.7	8.8	1.0	10.0	1.0	11.0	ns
		2OE to 2Y; see Fig. 6	[1]								
		V _{CC} = 3.0 V to 3.6 V	[2]								
		C _L = 15 pF		-	6.3	9.7	1.0	11.5	1.0	12.5	ns
		C _L = 50 pF		-	9.0	13.2	1.0	15.0	1.0	16.5	ns
		V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	4.3	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF		-	6.1	8.8	1.0	10.0	1.0	11.0	ns
C _{PD}	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	[4]	-	10	-	-	-	-	-	pF

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			I	Min	Тур	Max	Min	Max	Min	Max	1
74AHCT	2G241-Q100	1							1	1	
t _{pd}	propagation	nA to nY; see Fig. 4	[1]								
	delay	V_{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	3.4	5.5	1.0	6.5	1.0	7.0	ns
		C _L = 50 pF		-	4.7	7.5	1.0	8.5	1.0	9.5	ns
t _{en}	enable time	1OE to 1Y; see Fig. 5	[1]								
		V_{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	3.9	5.1	1.0	6.0	1.0	6.5	ns
		C _L = 50 pF		-	5.1	7.5	1.0	8.5	1.0	9.5	ns
		2OE to 2Y; see Fig. 6	[1]								
		V_{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	3.4	5.6	1.0	6.3	1.0	6.5	ns
		C _L = 50 pF		-	4.8	7.5	1.0	9.0	1.0	9.5	ns
t _{dis}	disable time	1OE to 1Y; see Fig. 5	[1]								
		V_{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	4.5	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF		-	6.1	8.8	1.0	10.0	1.0	11.0	ns
		2OE to 2Y; see Fig. 6	[1]								
		V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	4.0	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF		-	5.7	8.8	1.0	10.0	1.0	11.0	ns
C _{PD}	power dissipation capacitance	per buffer; C _L = 50 pF; f _i = 1 MHz; V _I = GND to V _{CC}	[4]	-	10	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 t_{en} is the same as t_{PZL} and $t_{\text{PZH}}.$

- t_{dis} is the same as t_{PLZ} and t_{PHZ} . Typical values are measured at V_{CC} = 3.3 V. [2]
- Typical values are measured at V_{CC} = 5.0 V. [3]
- C_{PD} is used to determine the dynamic power dissipation P_D (µW). $P_D = C_{PD} x V_{CC}^2 x f_i + \sum (C_L x V_{CC}^2 x f_o)$ where: [4]

 f_i = input frequency in MHz;

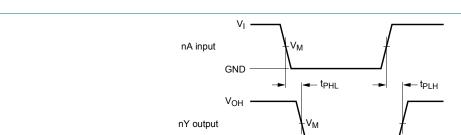
 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts.

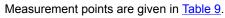
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Dual buffer/line driver; 3-state



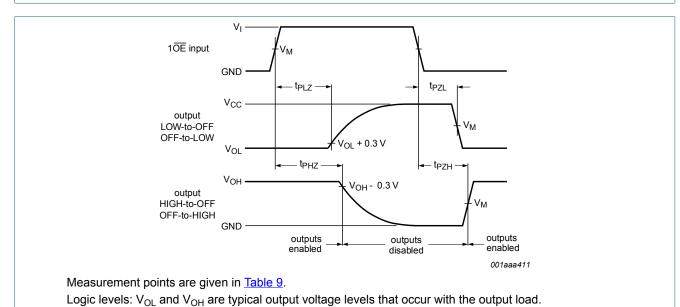
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11.1. Waveforms and test circuit



Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 4. The input (nA) to output (nY) propagation delays





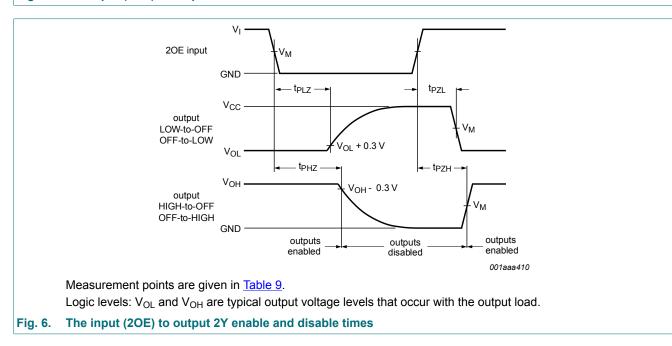
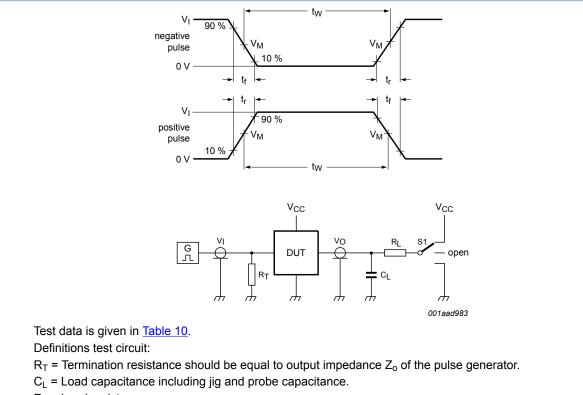


Table 9. Measurement points								
Туре	Input	Output						
	V _M	V _M						
74AHC2G241-Q100	0.5V _{CC}	0.5V _{CC}						
74AHCT2G241-Q100	1.5 V	0.5V _{CC}						



 R_L = Load resistance.

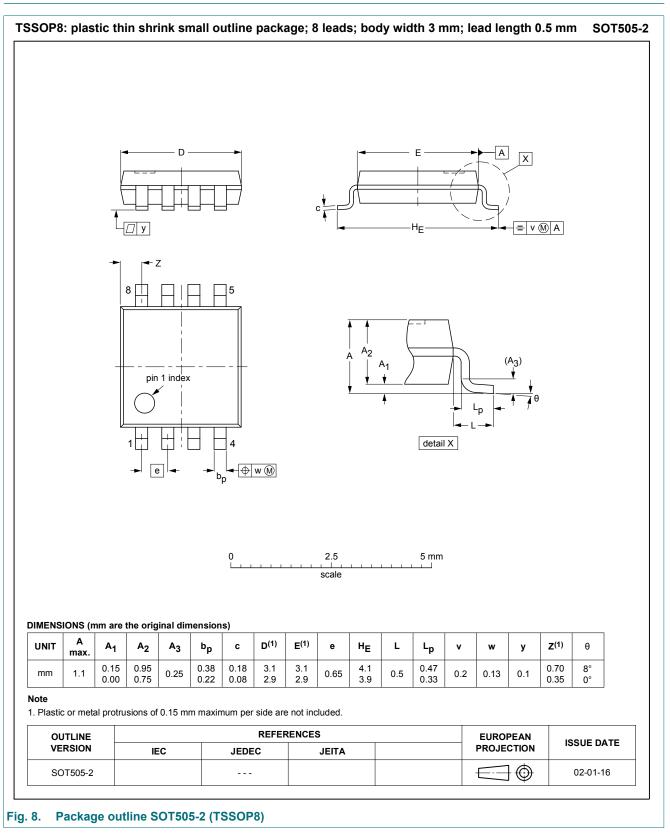
S1 = Test selection switch.

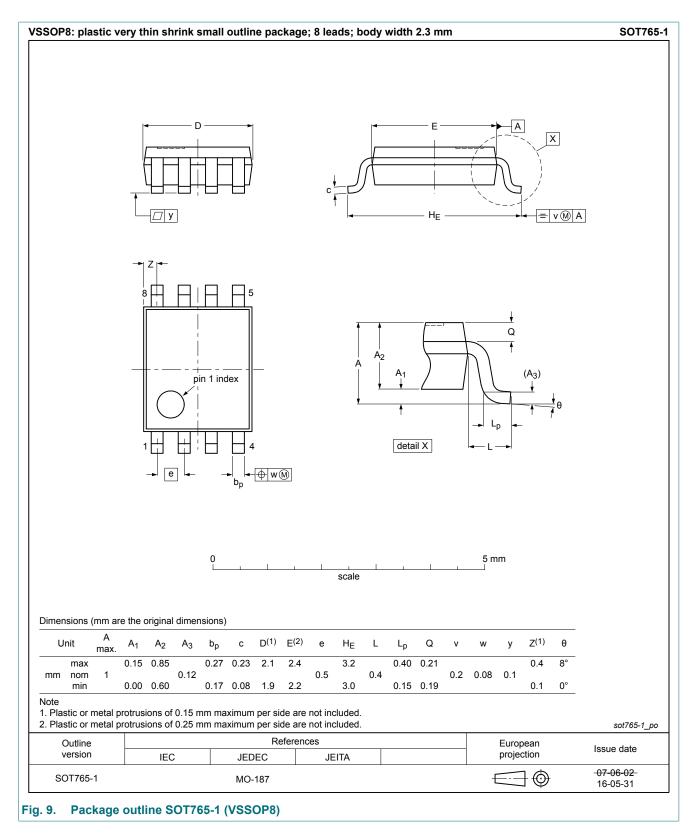
Fig. 7. Test circuit for measuring switching times

Table 10. Test data

Туре	Input		Load		S1 position			
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74AHC2G241-Q100	V _{CC}	≤ 3 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74AHCT2G241-Q100	3 V	≤ 3 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

12. Package outline





13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 12. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AHC_AHCT2G241_Q100 v.2	20190116	Product data sheet	-	74AHC_AHCT2G241_Q100 v.1			
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74AHCT2G241DP-Q100 removed. 						
74AHC_AHCT2G241_Q100 v.1	20130513	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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Dual buffer/line driver; 3-state

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